# NSN 5961-01-014-1599

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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.250 inches and 0.340 inches

# **Overall Diameter:**

0.620 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

## **Criticality Code Justification:**

Feat

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

375.0 breakdown voltage, collector-to-base, emitter open and 250.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

2.00 amperes source cutoff current and 1.00 amperes source cutoff current

# Power Rating Per Characteristic:

2.5 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Item must comply with rqmt of desc production standard no. L01916; junction pattern arrangement: npn

## Terminal Type And Quantity:

1 case and 2 pin

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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